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Influence of Deposition Time Variation on the Structural and Electrochemical Properties of Fe₂O₃ Thin Films via SILAR for Supercapacitor Applications

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Abstract

In this study, we successfully synthesized small granular ferric oxide (Fe₂O₃) thin films on stainless steel (SS) using successive ionic layer adsorption and reaction (SILAR) technique. The optimized Fe₂O₃ thin films underwent comprehensive physical characterization, revealing a hexagonal structure via X-ray diffraction (XRD). Field Emission Scanning Electron Microscopy (FE-SEM) confirm a small granular morphology. Electrochemical performance was assessed through cyclic voltammetry (CV), galvanostatic charge-discharge (GCD), and electrochemical impedance spectroscopy (EIS). The Fe₂O₃ nanograins demonstrated a high specific capacitance (Cs) of 744.7 F/g. Specific energy (SE) and specific power (SP) values peaked at 75.2 Wh/kg and 1.3 kW/kg, respectively, at 1 mA/cm² in a 1M KOH electrolyte. The EIS analysis confirmed an internal resistance (Ri) of 1.4 Ω, indicating excellent power concert and rate ability. These findings underscore the efficacy of the SILAR method in producing high-performance Fe₂O₃ nanostructures for supercapacitor applications, offering a cost-effective and scalable approach for energy storage solutions.

Keywords: Fe₂O₃, Small granular morphology, SILAR, Supercapacitor, Thin film.

1. Introduction

The escalating request for sustainable and competent energy device solutions have driven significant research into advanced energy storage devices. Among these, supercapacitors stand out due to their superior power density, fast charge-discharge proficiencies, and long cycle life, construction them ideal for a extensive range of applications, from transferable electronics to grid-scale energy storage and electric vehicles [1][2][3][4]. One of the critical components influential the performance of supercapacitors is an electrode material. In this context, ferric oxide (Fe_2O_3) has emerged as a highly promising candidate. Ferric oxide, commonly known as hematite, is an iron oxide that offers several advantages for supercapacitor applications. It is abundantly available, environmentally friendly, and cost-effective, which makes it suitable for scalable production. Fe_2O_3 possesses a high theoretical capacitance due to its multiple oxidation states, enabling it to undergo various redox reactions essential for charge storage and release. Additionally, Fe_2O_3 exhibits good chemical stability and can be engineered into various nanostructures, which significantly enhance its electrochemical properties via increasing an active surface area and facilitating efficient electron transport [2][3][5][6][7][8].

In this study, we employed the SILAR method to manufacture Fe_2O_3 thin films, focusing on the effects of varying the deposition (or "deepening") time on their structural and electrochemical properties. The SILAR technique is advantageous for the deposition of thin films due to its simplicity, low cost, and accurate control over film thickness and alignment [9][10][11][12][13][14]. This method involves the alternate involvement of a substrate into solutions containing cationic and anionic solution, allowing for the gradual build-up of the desired material layer by layer. By varying the immersion times in each precursor solution, we can systematically study and optimize the growth conditions to achieve the best possible performance for supercapacitor. The prime goal of this research has to understand how changes in deepening time during the SILAR process influence the crystallinity, morphology, and electrochemical behavior of Fe_2O_3 thin films. Comprehensive physical characterization was performed using XRD to identify the crystallographic structure of a films, which revealed a well-defined cubic phase characteristic of high-quality Fe_2O_3 [15][16][17][18]. FE-SEM was utilized to examine a surface morphology, showing granular structures that provide a high surface area, crucial for enhancing electrochemical activity.

In the present investigation, the Fe_2O_3 film was manufactured by SILAR technique, since a SILAR technique was used to synthesize a uniform film at room temperature. A present study rumors on a synthesis of a small grain like network of Fe_2O_3 film on SS substrate by a simple and low-cost SILAR technique. Using XRD, FE-SEM, and EDAX, the structural, morphological, and electrochemical characteristics of a deposited films were examined.

2. Experimental

2.1 Materials

Ferric nitrate formula [$\text{Fe}(\text{NO}_3)_3$] (99% extra pure). sodium hydroxide pellets [NaOH] (98% extra pure), hydrochloric acid [HCl], and acetone. All chemicals bought from SDFCL chemical Ltd. All chemicals were used without using extra purification. Stainless steel (SS) was used as a conducting working electrode.

2.2 Substrate Cleaning

The SS substrate was primarily polished by polish paper and then rinsed in distilled water (DW), ultrasonicated in an acetone solution for 30-40 minutes, and dried in an oven at 333 K. After being repeatedly ultrasonicated in a 10 % HCl solution for 10 minutes, they were frequently cleaned with DW. An airtight container was utilized to store all of a ready substrates for use throughout the synthesis [10].

2.3 Synthesis of Fe₂O₃ thin film electrode

We synthesized Fe₂O₃ thin films using the SILAR method, with a specific focus on varying dipping times to determine their impact on the film properties. The cation solution used was 0.2 M Fe(NO₃)₃, and the anion solution was 0.2 M NaOH. The deposition process involved 50 cycles of immersion, utilizing a four-beaker setup that included sequential dipping into the cation solution (Fe³⁺ ions), distilled water, the anion solution (OH⁻ ions), and another distilled water rinse. We varied the immersion times among three different sets: 20-10-20-10 seconds (DF1), 30-10-30-10 seconds (DF2), and 40-10-40-10 seconds (DF3), where the first and third values correspond to the dipping times in the cation and anion solutions, respectively, and the second and fourth values correspond to the dipping times in the distilled water rinses. Following the deposition cycles, the films were calcined at 623K to promote crystallization and ensure the formation of Fe₂O₃. This methodological variation allowed us to systematically investigate the influence of dipping time on the structural and morphological characteristics of the synthesized Fe₂O₃ thin films [10][9].

2.4 Electrochemical measurements

To estimate electrochemical properties, we utilized CV, GCD, and EIS with an HCH 600D SPL electrochemical analyzer. A standard three-electrode setup had employed, using a 1 M KOH solution as the electrolyte. A working electrodes were a Fe₂O₃ electrode, the counter electrodes were a platinum wire, and an Ag/AgCl as a reference electrode. CV measurements were conducted at scan rates from 5 to 100 mV/s within a voltage window of -1.47 to 0.0 V. CP measurements was carried out at current densities from 1 to 5 mA/cm² at a constant potential of 1.47 V. The specific capacitance (C_s) of the materials was calculated using the appropriate formula for these measurements [10][9].

$$C_s = \frac{1}{mv(v_f - v_i)} \int_{v_i}^{v_f} I(V) dv \quad (1)$$

$$SE = \frac{V \times I_d \times t_d}{m} \quad (2)$$

$$SP = \frac{V \times I_d}{m} \quad (3)$$

$$\eta(\%) = \frac{t_d}{t_c} \times 100 \quad (4)$$

Where (V_f - V_i) potential window, 'm' active mass on an electrode, 'v' sweep rate in mV/s, 'I (V)' current in mA, 'I_d' discharge current, and 't_c' charging time in sec., 't_d' discharge time in sec.

2.5 Characterization details

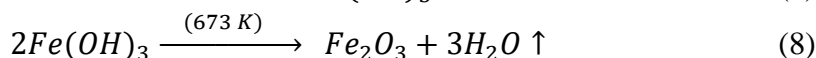
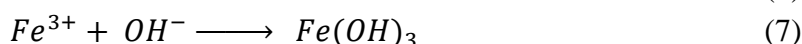
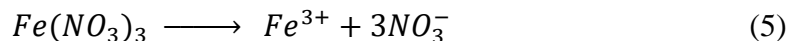
The crystal structure with plane orientations of the samples were resolute using XRD analysis with a Rigaku D/max 2550 Vb+/PC diffractometer, utilizing Cu K α radiation ($\lambda = 1.5406 \text{ \AA}$). A microstructure was examined using a Hitachi S-4800 FE-SEM operating at 15 kV. Wettability studies of the fabricated electrodes were conducted using a Holmark HO-IAD-CAN-01 apparatus. The weight of the deposited material had measured with a high-precision systematic microbalance (Tapson's-100 TS) using the weight difference method.

Electrochemical properties of Fe₂O₃ film electrodes were evaluated in a three-electrode setup using a computer-controlled potentiostat (HCH 600D SPL electrochemical analyzer/workstation). In this setup, a saturated Ag/AgCl electrode served as the reference, a platinum wire as the counter electrode, and the working electrode was a Fe₂O₃ film (1.5×1.5 cm²) immersed in the electrolyte. Cyclic voltammetry (CV) plots were obtained to calculate the specific capacitance (Cs). Charge-discharge characteristics were studied using galvanostatic charge-discharge (GCD) at different current densities to calculate specific energy (SE) and specific power (SP). The EIS was performed with an AC signal over a frequency range of 100 Hz to 1 MHz to evaluate the internal resistance of a supercapacitor.

3. Results and discussion

3.1 Reaction kinetics

We synthesized Fe₂O₃ electrode using the SILAR method, employing 0.2 M Fe(NO₃)₃ as the cation source and 0.2 M NaOH as the anion source. During each cycle, Fe³⁺ ions adsorbed onto the substrate react with OH⁻ ions to form Fe(OH)₃, which is converted to Fe₂O₃ upon calcination. The repeated immersion and rinsing ensure the formation of a uniform and pure Fe₂O₃ film, with the dipping time optimization enhancing the film's crystallinity and uniformity [19][20]:



The final optimized electrode of Fe₂O₃ used for dissimilar physical and chemical characterization methods.

3.2 Structural analysis

The X-ray diffraction (XRD) analysis depicted in **Fig. 1** showcases the patterns of pure Fe₂O₃ thin films deposited on stainless steel (SS) substrates. Remarkably, the observed d-spacing values precisely matched the standard d-values extracted from the JCPDS data card No. 33-0664 for Fe₂O₃. Evidently, distinct peaks emerged at angles 2θ = 43.4°, 44.4°, 50.6°, 64.4°, 74.4°, and 81.9°, corresponding to crystal planes (113), (202), (024), (300), (220), and (015), respectively. This alignment unequivocally confirms hexagonal crystal structure of Fe₂O₃. Notably, the intensity of the peak at 2θ = 44.4° (202) significantly stands out, indicative of a highly crystalline structure. Such pronounced intensity underscores the well-ordered arrangement of atoms or molecules within the Fe₂O₃ lattice, characteristic of crystalline materials. Consistent with prior findings by Xia *et al.* [21], these results reaffirm the hexagonal crystal structure of Fe₂O₃ nanoparticles. Moreover, the absence of additional phase peaks signifies complete conversion of the deposited hydroxide into Fe₂O₃. By applying Scherrer's equation [22], the crystallite sizes (D) were estimated, revealing average sizes of around 56.3 nm, 39.1 nm, and 42.8 nm for samples DF1, DF2, and DF3, respectively. These findings underscore the successful synthesis of highly crystalline Fe₂O₃ thin films, demonstrating distinct crystallite sizes attributed to variations in the SILAR method's dipping times.

$$D = \frac{K\lambda}{\beta \cos\theta} \quad (9)$$

Where, 'K' constant (0.9), ' λ ' wavelength of X-ray, ' β ' full-width half maximum (FWHM), and ' θ ' Bragg's angle.

The following formula was used to determine the microstrain: Eq. (10).

$$\varepsilon = \frac{\beta}{4 \tan \theta} \quad (10)$$

The intended value of the micro-strain of samples DF1, DF2, and DF3 was 0.0328, 0.0592, 0.0443 respectively.

The subsequent formula was used to regulate the dislocation density: Eq. (11)

$$\delta = \frac{1}{D^2} \quad (11)$$

The intended value of a dislocation density [23] of Fe_2O_3 was 3.49, 5.39, 4.51, of DF1, DF2, and DF3 respectively shown in **Table 1**.

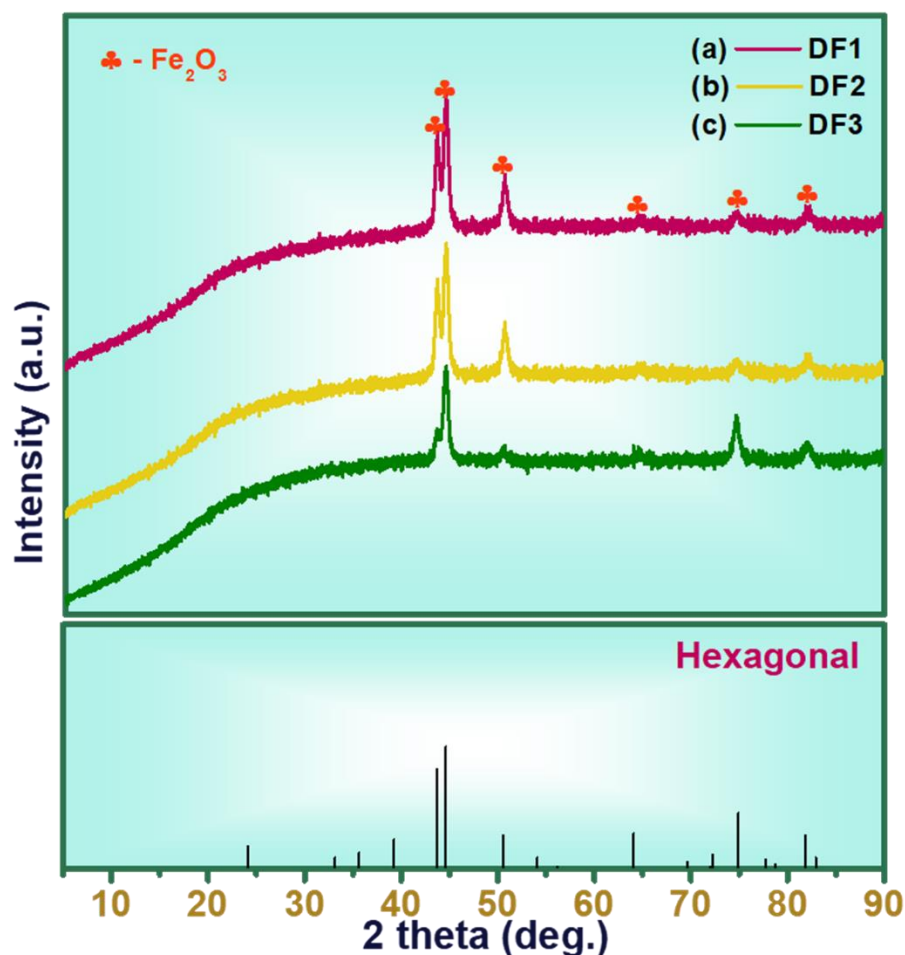


Fig 1: XRD plots of sample (a) DF1, (b) DF2, and (c) DF3

Sample code	Crystallite size (D) (nm)	Micro strain (ε) (10^{-3})	Dislocation density (δ) ($\times 10^{15}$) lines m^{-2}
DF1	56.3	0.0328	3.49

DF2	39.1	0.0592	5.39
DF3	42.8	0.0443	4.51

Table 1: Structural variation of DF1, DF2, and DF3 electrode in terms of crystalline size, micro strain, and dislocation density.

3.3 FE-SEM and EDAX analysis

Fig 2 (a-f) illustration the FE-SEM images of sample DF2 and DF3 by adjusting the immersion times in each solution, we created two distinct samples designated DF2 and DF3 each with different cycle variations. Upon FE-SEM imaging at magnifications of 10 μm and 1 μm , we observed a granular morphology consistent across all samples, indicative of small grain-like structures. Notably, the higher resolution 1 μm images provided finer details of the grain structure similar result reported by Nehru *et al.* [24]. Further analysis revealed sample DF3 to possess the smallest grain size at 42.6 nm, while DF2 exhibited a slightly larger grain size of 46.2 nm. These findings underscore the significant effect of deposition cycle variations on the morphology and grain size of Fe_2O_3 . The observed grain-like morphology suggests the potential for enhanced surface area and reactivity, crucial factors for numerous applications. Understanding and controlling the grain size and morphology of Fe_2O_3 thin films hold promise for tailoring their properties to specific applications, offering avenues for further research and development in nanomaterials synthesis and engineering. In **Fig. 3 (a)**, the presence of chemical elements crucial for Fe_2O_3 , notably Fe and O, was verified through Energy Dispersive X-ray Analysis (EDAX). The substantial composition analysis yielded weight percentages of 96.08% for Fe and 3.92% for O, indicating the predominant presence of iron oxide in the synthesized nanomaterials. Additionally, the atomic percentages of Fe and O were determined to be 87.53% and 12.47%, respectively, reaffirming the elemental composition consistent with Fe_2O_3 . Further insights into the elemental distribution and spatial arrangement were obtained through elemental mapping analysis, as illustrated in **Fig. 3 (b-d)** for the DF2 sample. The elemental mapping images clearly depict the occurrence of Fe and O throughout a sample, confirming the homogeneous distribution of these chemical elements. The utilization of EDAX mapping enabled a comprehensive understanding of the chemical composition and distribution of Fe_2O_3 nanomaterials, validating their suitability for various applications in catalysis, sensing, and energy storage.

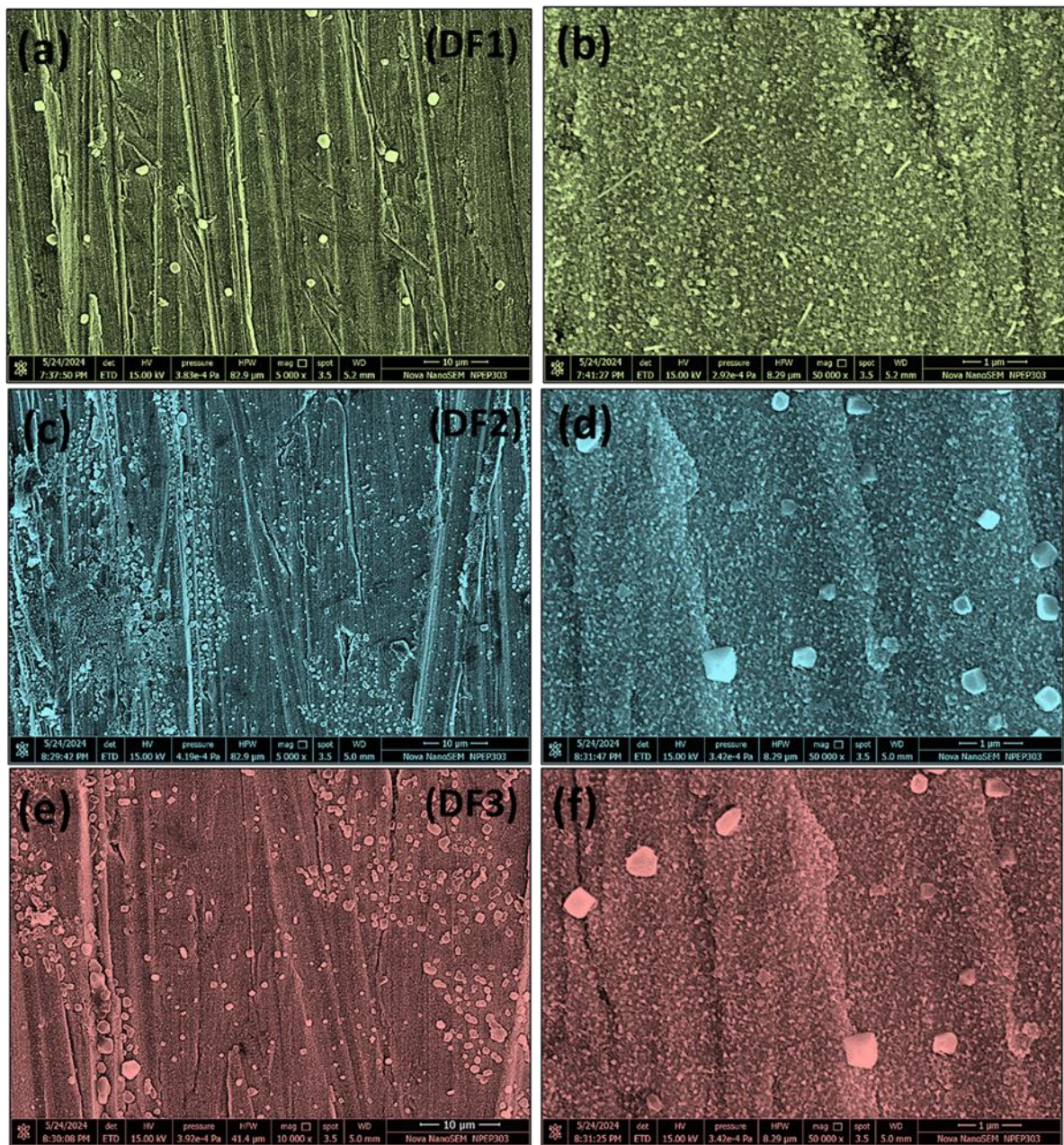


Fig 2: FE-SEM images of typical samples (a-b) DF1, (c-d) DF2, (e-f) DF3.

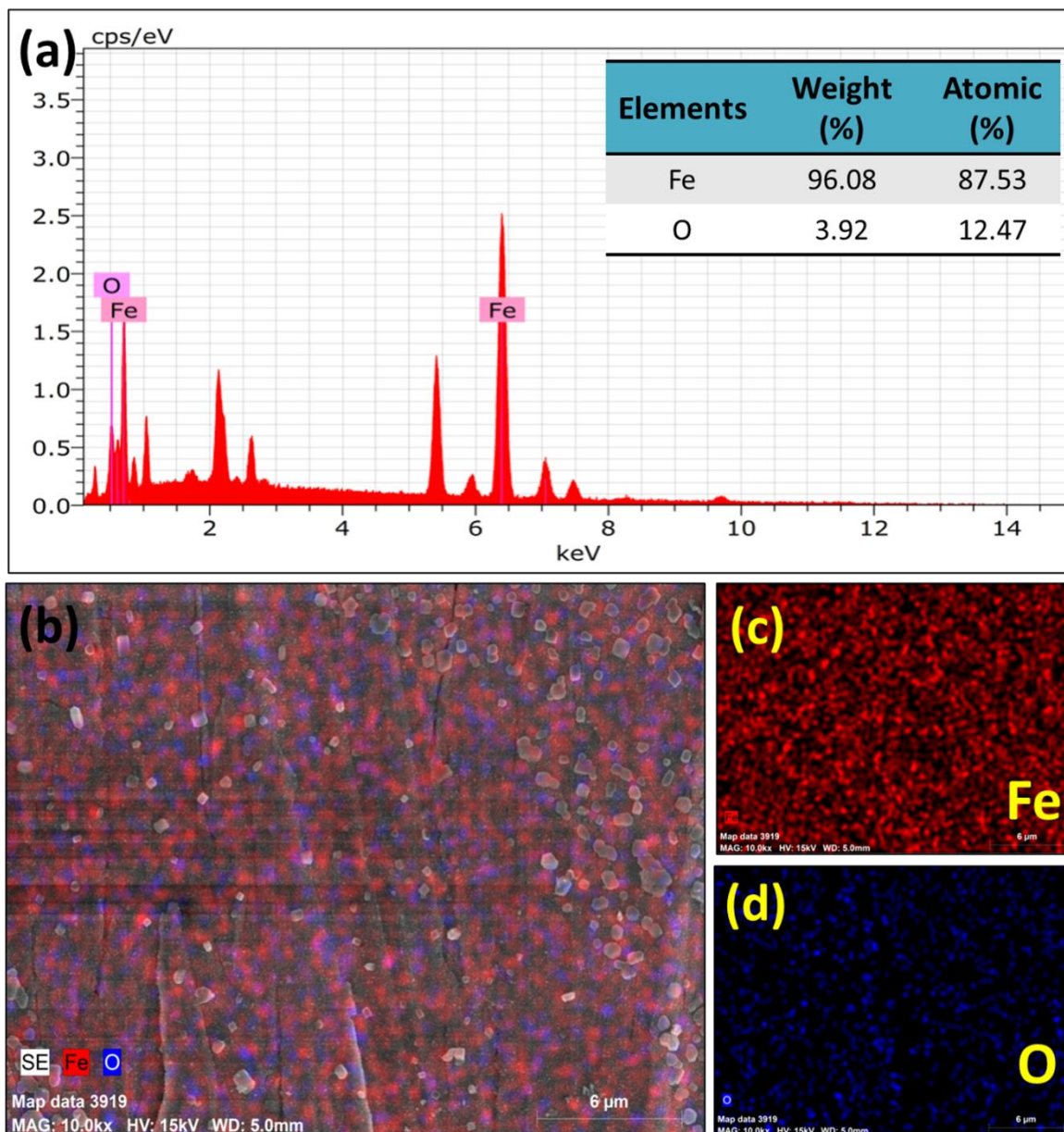


Fig 3: (a) EDAX spectrum with percentage of chemical elements present in DF2 electrode, (b) The EDAX mapping image of DF2 electrode, and (c-d) Elemental mapping images showing the individual distribution of Fe, and O.

3.4 Wettability study

The wettability of Fe_2O_3 thin films synthesized via the SILAR method was investigated through contact angle measurements. Varying the immersion times during deposition resulted in three distinct samples. The contact angle measurements revealed differences in wettability among the samples, with contact angles of 80.7° , 78° , and 93° observed for DF1, DF2, and DF3, respectively show in **Fig 4 (a-c)**. The contact angle serves as a crucial indicator of surface hydrophobicity or hydrophilicity, with smaller contact angles indicating higher hydrophilicity and larger angles suggesting greater hydrophobicity. The observed contact angles suggest that sample DF1 exhibits the highest hydrophilicity, followed by DF2, while DF3 demonstrates the highest degree of hydrophobicity among the samples. These findings offer valuable insights into the surface properties of Fe_2O_3 thin films,

which are essential for various applications. The variation in contact angles among the samples underscores the significance of deposition parameters in tailoring surface properties.

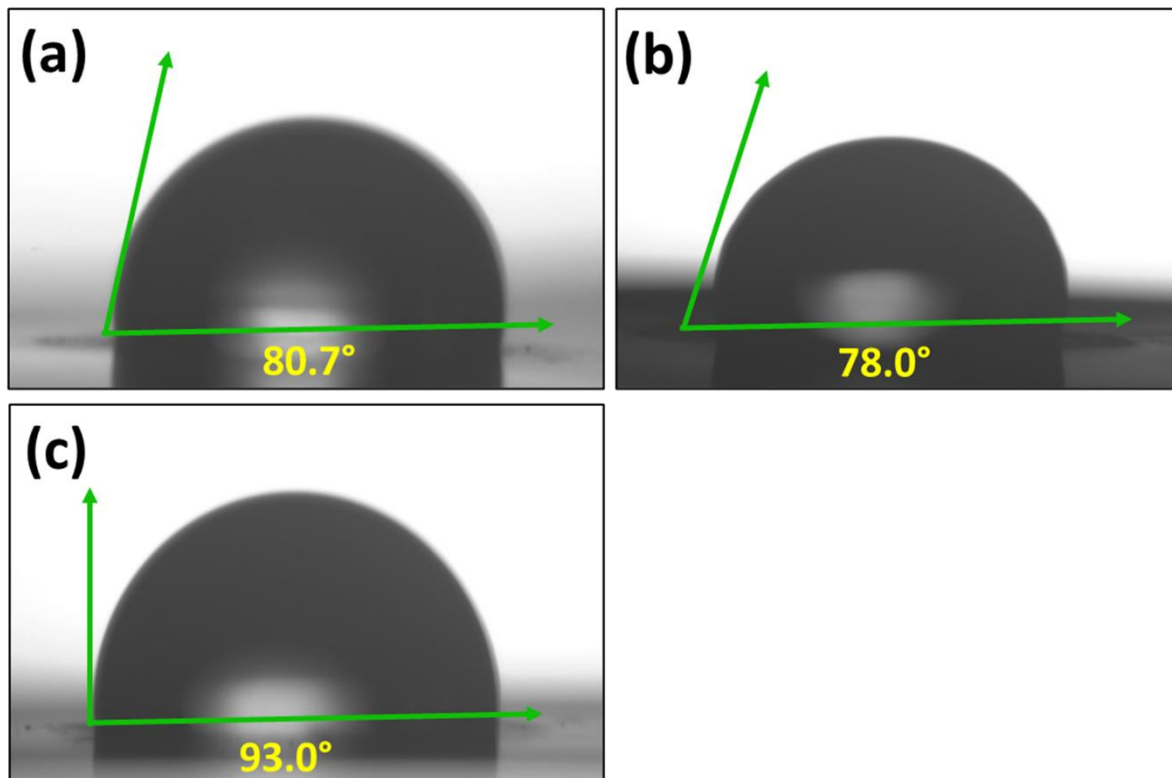


Fig 4: Contact angle of sample (a) DF1, (b) DF2, (c) DF3.

3.5 Electrochemical analysis

3.5.1 Cyclic voltammetry analysis

In our investigation Fe_2O_3 thin film was synthesized using SILAR method, with variations in deposition cycles resulting in distinct morphologies and electrochemical properties. Samples DF1, DF2, and DF3, corresponding to different immersion time variations show in **Fig. 5 (a)**. Through CV analysis, DF2 demonstrated the highest C_s of 744.7 F/g at a sweep rate of 5 mV/s in 1 M KOH electrolyte, surpassing DF1 and DF3 with specific capacitances of 520.8 and 512 F/g, respectively show in **Fig. 5 (b)**. This enhancement in C_s of DF2 can be attributed to its finer grain size, higher crystallinity, and improved wettability angle, reflecting enhanced electrode-electrolyte interactions. Furthermore, the potential window for these measurements ranged from -1.47 to 0 V vs Ag/AgCl, providing insights into the electrochemical stability of Fe_2O_3 thin film electrodes [1][5]. These findings underscore the significant impact of deposition constraints on both a morphological and electrochemical properties of Fe_2O_3 electrode, holding promise for their application in advanced energy devices. **Table 2** show the variation of C_s in F/g at sweep rate of 5 mV/s for dissimilar electrode (DF1, DF2, DF3).

The optimization achieved through Deeping time variation resulting in the final electrode denoted as DF2. To comprehensively assess the electrochemical performance of DF2, CV analyses were conducted at various sweep rates ranging from 5 to 100 mV/s in 1 M KOH electrolyte show in **Fig. 5 (c)**. Notably, DF2 exhibited specific capacitance values of 744.7, 663.5, 661.7, 650.6, and 645.3 F/g at sweep rates of 5-100 mV/s, respectively show in

Fig. 5 (d). and all data summarized in **Table 3**. These results underscore the remarkable capacitance retention of DF2 across a wide range of scan rates, indicative of its excellent charge storage capability and electrochemical permanency. Additionally, a potential window for these measurements spanned from -1.47 to 0 V vs Ag/AgCl, highlighting an electrochemical stability of a Fe₂O₃ thin film electrode. The observed trends in specific capacitance with varying scan rates provide valuable insights into the charge storage mechanisms and kinetics of DF2 [10][19], essential for its application in energy storage devices and electrochemical systems requiring high performance and reliability. **Table 4** show the evaluation of electrochemical characteristics of Fe₂O₃ by other described other metal oxide-based thin film in aqueous electrolyte

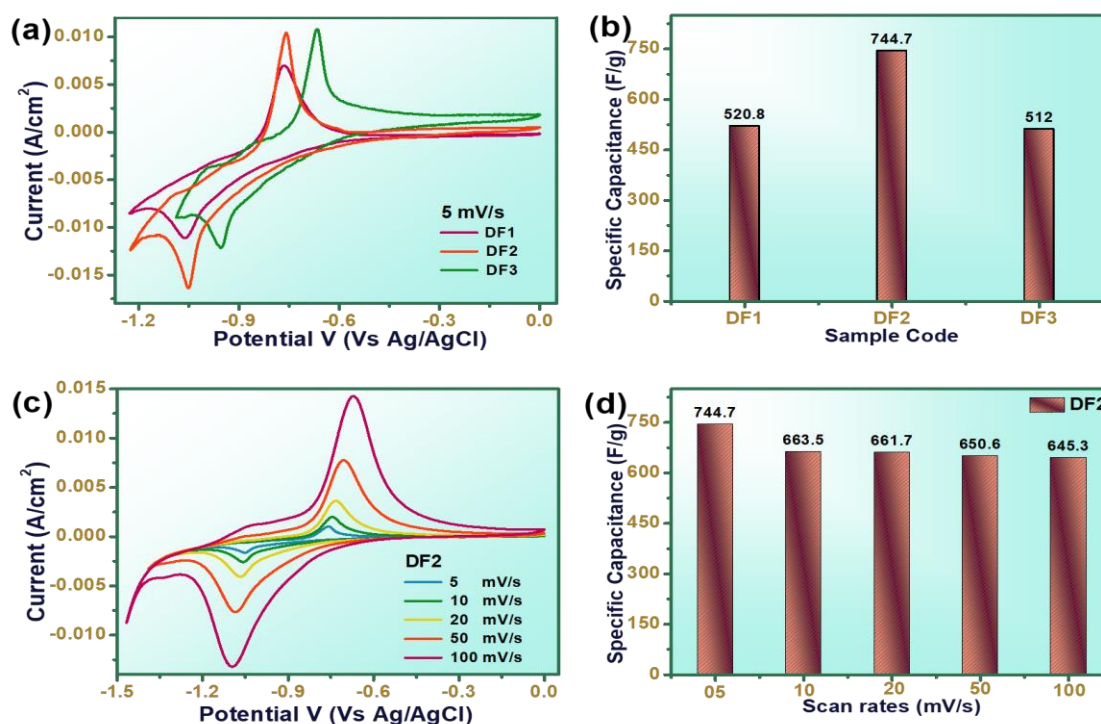


Fig 5: (a) CV plots of electrode DF1, DF2, and DF3, (b) specific capacitance vs sample code at 5 mV/s, (c) CV plots electrode DF2 at sweep rate of 5 -100 mV/s in 1 M KOH, (d) specific capacitance vs sweep rate in mV/s of electrode DF2.

Sample code	Cs in F/g at scan rate of 5 mV/s
DF1	520.8
DF2	744.7
DF3	512

Table 2: Variation of Cs in F/g at scan rate of 5 mV/s for different electrode.

Scan rate in mV/s	Cs in F/g
05	744.7

10	663.5
20	661.7
50	650.6
100	645.3

Table 3: Variation of Cs in F/g at different scan rate of DF2 electrode.

Material	Synthesis method	Electrolyte	Potential window	Cs (F/g)	Ref.
Fe ₂ O ₃	hydrothermal	2M KOH	-1.2 - 0 V vs SCE	558.6	2
Fe ₃ O ₄	Ultrasonication	1M Na ₂ SO ₃	-0.9 - 0.1 V vs Hg/HgO	207.7	4
FeOOH	Low temperature hydrothermal	2M KOH	-1.2 - 0 V vs SCE	714.8	5
Bi ₂ WO ₆	Sonochemical	1M KOH	-0.9 - 0.1 V vs Hg/HgO	304	6
MoO ₂	Template synthesis	1M LiOH	-1.2 - -0.5 V vs SCE	146	8
MnFe ₂ O ₄ /G	Hydrothermal	1M Na ₂ SO ₄	-0.8 - 0 V vs Ag/AgCl	221	9
TiN	Hydrothermal	1M KOH	-1.0 - 0 V vs Ag/AgCl	123	10
Fe ₂ O ₃	SILAR	1M HOH	-1.47 - 0 V vs Ag/AgCl	744.7	Current working

Table 4: Comparison of Fe₂O₃ electrode with other reported other metal oxide-based thin film in aqueous electrolyte.

3.5.2 Chronopotentiometry analysis

The thin film electrodes Fe₂O₃ was synthesized using the SILAR method, employing varying Deeping times to produce electrodes denoted as DF1, DF2, and DF3. **Fig. 6 (a)** show the evaluate their electrochemical performance, GCD analyses were conducted at a fixed current density of 1 mA/cm² in a 1 M KOH electrolyte. The GCD plots revealed specific energy values of 33.1, 75.2, and 44.3 Wh/kg, specific power values of 1.4, 1.3, and 1 kW/kg, and efficiencies of 39.8%, 55.3%, and 49.5% for DF1, DF2, and DF3, respectively show in **Fig. 6 (b)** and all data summarized in **Table 5**. These results demonstrate the superior performance of electrode DF2, characterized by significantly higher specific energy and power values compared to DF1 and DF3. The observed efficiencies reflect the effectiveness of each electrode in storing and releasing electrical energy during charge-discharge cycles

[12][9]. Moreover, the potential window for these measurements ranged from -1.47 to 0 V vs Ag/AgCl, highlighting the electrochemical stability of the Fe₂O₃ thin film electrodes.

Fig. 6 (c) show the Fe₂O₃ thin film electrode DF2 was synthesized using the SILAR method, optimized through Deeping time variation, and evaluated through GCD analysis. The GCD plots for DF2 were found at various current densities of 1-5 mA/cm² in a 1 M KOH electrolyte, revealing specific energy values of 75.2, 31.2, 24.4, 19.2, and 17.3 Wh/kg, respectively. Correspondingly, the specific power values were determined to be 1.3, 2.6, 4, 5.3, and 6.6 kW/kg, with efficiency percentages of 55.3%, 71.7%, 70.4%, 75%, and 61.5%, respectively show in **Fig. 6 (d)**. These results highlight the high SE and SP capabilities of DF2, particularly at lower current densities, where the efficiency is maximized at moderate current densities and slightly decreases at higher densities. The potential window for these measurements was maintained from -1.4 to 0 V vs Ag/AgCl, ensuring an electrochemical stability of the Fe₂O₃ electrode [15][22]. The superior performance metrics of DF2, particularly its high SE and SP, combined with notable efficiency, underscore its potential for high-performance energy applications. **Table 6** show the SE, SP, and efficiency of DF2 electrode at different current density.

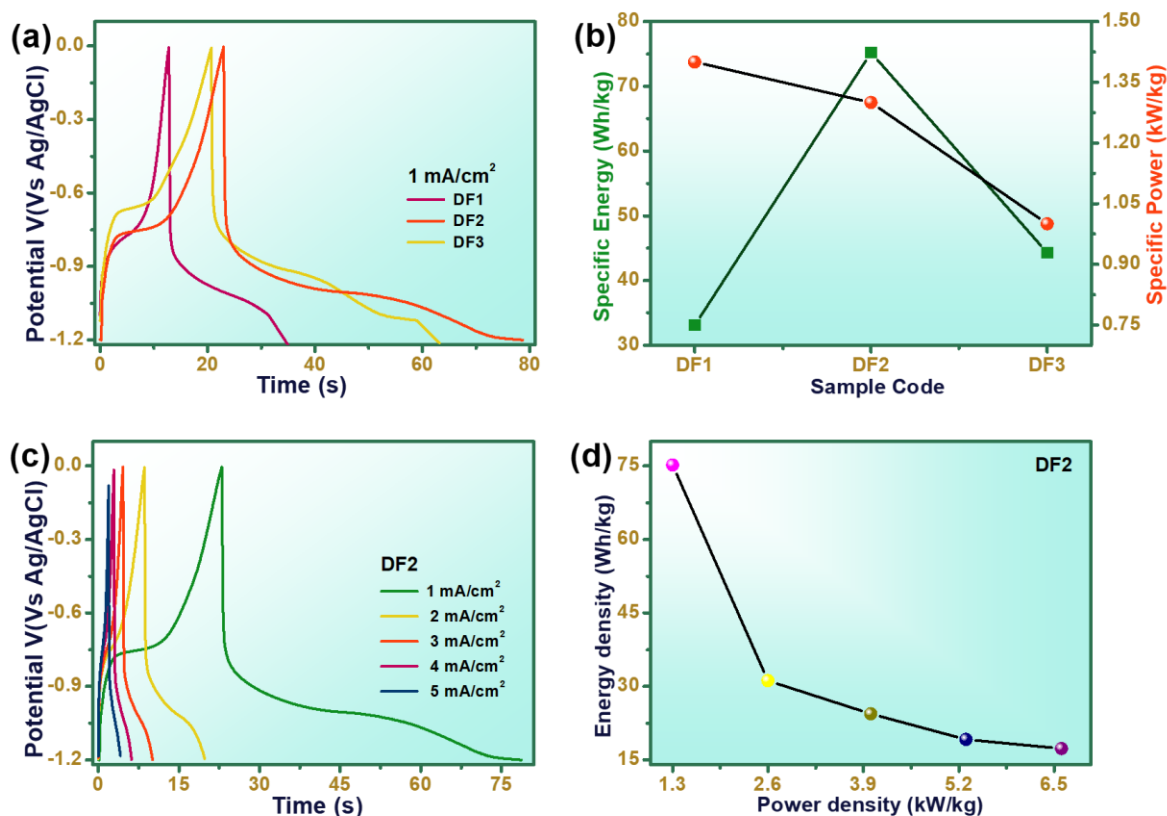


Fig 6: (a) The GCD curves of Fe₂O₃ at 1 mA/cm² in 1M KOH electrolyte, (b) region plots of different electrode DF1, DF2, and DF3, (c) The GCD plots of electrode DF2 at dissimilar current density from 1-5 mA/cm² in 1M KOH electrolyte, (d) region plot SE vs SP of electrode DF2.

Sample code	Specific energy in (Wh/kg)	Specific power in (kW/kg)	Efficiency in (%)
DF1	33.1	1.4	39.8
DF2	75.2	1.3	55.3
DF3	44.3	1	49.5

Table 5: SE, SP, and efficiency of DF1, DF2, and DF3 electrode

Current density (mA)	Specific energy in (Wh/kg)	Specific power in (kW/kg)	Efficiency in (%)
1	75.2	1.3	55.3
2	31.2	2.6	71.7
3	24.4	4	70.4
4	19.2	5.3	75
5	17.3	6.6	61.5

Table 6: Specific energy, specific power, and efficiency of DF2 electrode at different current density.

3.5.3 Electrochemical impedance spectroscopy analysis

Fig. 7 (a) presents a Nyquist plot used to evaluate an internal resistance and capacitive performance of Fe₂O₃ electrodes DF1, DF2, and DF3 via EIS in a 1M KOH over a frequency ranging of 100 Hz to 1 MHz. The plot was separated into three distinct regions: the low-frequency area indicating pseudocapacitive behavior, and the high-frequency area showing a charge transfer resistance (R_{ct}) of a Faradaic reaction, represented by a depressed semicircle. The internal resistance (R_i) values were measured to be 1.2 Ω for DF1, 1.5 Ω for DF2, and 2 Ω for DF3. Additionally, the knee frequency, which signifies the highest frequency where capacitive performance is dominant, marks the transition from the semicircular to the linear region in the plot [1][10].

The Nyquist plot for a DF2 electrode, revealed in **Fig. 7 (b)**, includes both the experimental data and the curve fit analyzed using ZsimpWin simulation software. An inset of **Fig. 7 (b)** presents the equivalent circuit for the DF2 electrode, with circuit parameters including a series resistance (R_s) of 1.556 Ω, charge transfer resistance (R_{CT}) of 13.09 Ω, leakage resistance (R_L) of 0.4808 Ω, two constant phase elements (CPE) of 1.327×10⁻³ F and 8.79 ×10⁻⁵ F, and a Warburg impedance (W) of 1.986×10⁻³ F. Additionally, **Fig. 7 (c)** displays the Bode plot for the DF2 electrode, recorded at open circuit potential (OCP) of -0.4793 V with a 5 mA current in 1M KOH [10] [9][22]. This plot illustrates that as a frequency increases, a phase angle also increases, indicating predominant capacitive performance at the knee frequency. As frequency increases, the phase angle decreases,

signifying a evolution from capacitive to resistive performance. At lower frequencies, the material exhibits capacitive properties, while at higher frequencies, resistive properties dominate. **Fig. 7 (d)** demonstrates a Bode plot for the DF2 electrode, recorded at OCP of -0.7903 V with a 5mA current in a 1 M KOH solution. This plot, which shows the relationship between phase angle and frequency, was crucial for understanding the electrode's characteristics. In a low-frequency range, a phase angle approaches 70° , indicating that the electrode exhibits near-supercapacitive behavior (with a perfect supercapacitor showing a phase angle of 90°) [25] [20].

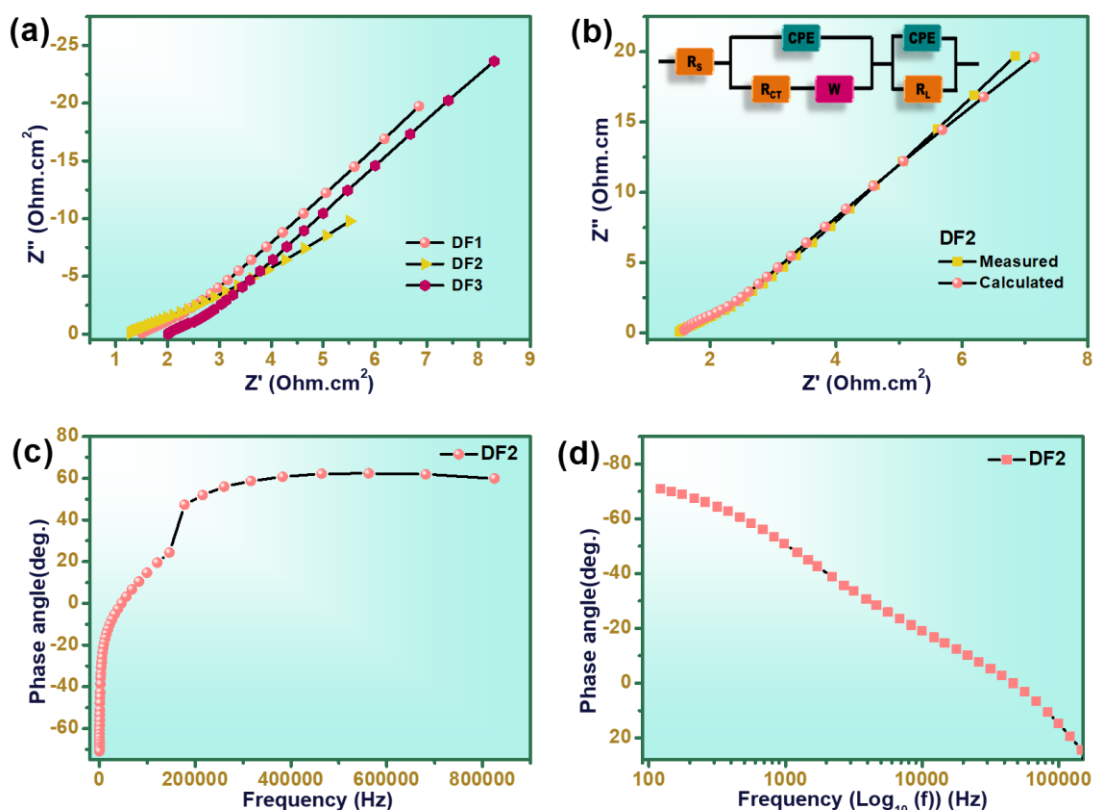


Fig. 7: EIS plot of sample electrode Fe₂O₃, (a) Nyquist plots of electrode DF1, DF2, and DF3, (b) nyquist plot & matched nyquist plot with marching circuit of electrode DF2, (c-d) bode plot of electrode DF2.

4. Conclusions

we successfully synthesized pure Fe₂O₃ electrodes using a simple and consistent one-step SILAR method with varied dipping times. The structural and morphological analysis via XRD and FE-SEM confirmed the hexagonal crystal structure and nanograin-like morphology of the Fe₂O₃ electrodes. The electrochemical performance was impressive, with the Fe₂O₃ electrode exhibiting a high specific capacitance (Cs) of 744.7 F/g at a scan rate of 5 mV/s. Additionally, the electrode achieved a maximum specific energy (SE) of 75.2 Wh/kg and a specific power (SP) of 1.3 kW/kg at current density of 1 mA/cm². These results designate that the interconnected Fe₂O₃ nanospheres suggestively enhance the endurance and performance of supercapacitors. Therefore, Fe₂O₃ proves to be a promising material for supercapacitor applications, providing an effective route for future energy storage solutions.

Institutional Review Board Statement: Not applicable.

Informed Consent Statement: Not applicable.

Data Availability Statement: Data will be made available on request.

Conflicts of Interest: The authors declare that they have no known competing financial interests or personal relationship that could have appeared to influence the work reported in this paper.

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